

# Volume Expansion and Stress Tensors for Self-Interstitial Aggregates in Diamond

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Fig. 3: Total energy of the A-centre vs. volume expansion  $(\eta)$ . The points are calculated, the solid line a quadratic fit. • Theory  $(\eta = 0.11)$  reproduces experiment very well.

# Dilatation of the Lattice Vacancy







Fig. 4: The difference in the radial distance of the shells of atoms surrounding the vacancy between the relaxed and unrelaxed tetrahedral structures (a positive deviation corresponds to an outward relaxation)

## Dilatation & B-tensors for interstitial aggregates

Table 2: Principal values and directions for the diagonal stress-energy tensors (eV per unit strain) and volume relaxation per interstitial (units of  $V_{ref}$ ) for interstitial aggregate models. n is the number of additional C atoms

| Defect                                      | n | $\eta/n$ | $B_1$                              | $B_2$                          | $B_3$         |
|---|---|----------|------------------------------------|--------------------------------|---------------|
| R2 expt <sup>†</sup>                        | 1 | -        | -24                                | 12                             | 12            |
| $I_1^{(001)}$ (R2)                          | 1 | 1.9      | -27.6                              | 13.8                           | 13.8          |
| Fig.1(a)                                    |   |          | [001]                              | [100]                          | [100]         |
| $I_2^{\rm NN}$ (R1)                         | 2 | 1.7      | -44.4                              | 41.9                           | 2.6           |
| Fig.1(b)                                    |   |          | $23^{\circ}$ to $[00\overline{1}]$ | $23^{\circ}$ to [110]          | $[1\bar{1}0]$ |
| $I_2^{2NN}$                                 | 2 | 1.7      | -55.6                              | 21.4                           | 34.3          |
| Fig.1(c)                                    |   |          | [001]                              | $[1\bar{1}0]$                  | [110]         |
| $(I_2^{2NN})^+$                             | 2 | 1.1      | -51.4                              | 18.1                           | 33.3          |
| Fig.1(c)                                    |   |          | [001]                              | $[1\bar{1}0]$                  | [110]         |
| $\pi$ - $I_2$                               | 2 | 1.7      | -66.0                              | 29.2                           | 36.4          |
| Fig.2(a)                                    |   |          | $6^{\circ}$ to $[1\bar{1}1]$       | $6^{\circ}$ to [ $\bar{1}12$ ] | [110]         |
| $I_3$ (O3)                                  | 3 | 1.6      | -89.7                              | 45.9                           | 43.8          |
| Fig.2(b)                                    | 0 |          | 2° to [001]                        | $2^{\circ}$ to [100]           | [010]         |
| $I_3:D_{2d}$                                | 3 | 1.6      | -100.1                             | 50.1                           | 50.1          |
| Fig.1(d)                                    |   |          | [001]                              | [100]                          | [010]         |
| $I_4$                                       | 4 | 1.5      | -120.5                             | 60.3                           | 60.3          |
| Fig.2(c)                                    |   |          | [001]                              | [100]                          | [010]         |
| † – values inferred from experimental data. |   |          |                                    |                                |               |



Fig. 1: Geometry of (a)  $I_1^{(001)}$  (R2), (b)  $I_2^{NN}$  (R1), (c)  $I_2^{2NN}$ (3H?) and (d) the low energy  $D_{2d}$  model for  $I_3$ . Interstitials atoms are shown shaded. 3- & 4-fold coordinated atoms being grey and black respectively.



Fig. 2: Geometry of (a) the  $\pi$ -bonded di-interstitial, (b)  $C_2$ symmetry  $I_3$  (O3), and (c)  $I_4$ . Shading as in Fig. 1.



#### References

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Abstract

There is a need for defect modelling techniques to be able to accurately calculate experimentally observable quantities. We present the results of the calculation of volume relaxations and piezospectroscopic stress tensors for proposed models of interstitial aggregates in diamond to facilitate correlation with the experimental centres

## Theoretical Outline

- Supercell, LSDF calculations: AIMPRO [1, 2]
- Cubic supercells: 64-216 atoms
- Cartesian Gaussian wavefunction basis
- Charge density treated by plane-waves
- BHS pseudopotentials [3]

## Volume dilation

Defects exerting a compressive strain on the surrounding lattice results in an expansion of the lattice. The fractional increase in volume is

T

$$\frac{\delta V}{V} = \eta \frac{[X]}{[C]}$$

[X] & [C] are the number densities of defect (X) and diamond sites. The volume change for a defect is then:

$$\delta V = \eta V_{
m ref}$$
  $V_{
m ref} = a_0^3/8$ 

#### Piezospectroscopic Stress Tensor

- No imposed stress: in equilibrium defects randomly oriented.
- Stress renders different orientations with different energies
- The change in energy is  $\Delta E = \text{Tr } B_i \cdot \epsilon$  $-\epsilon = \text{imposed strain}$
- $-B_i = (\text{traceless}) \text{ energy-stress tensor } [\text{defect orientation } i].$ • Equilibrium populations of defects aligned along i for
- temperature  $T \propto \exp(-\Delta E_i/kT)$ .
- The tensor does not depend on a reorientation barrier

## Interstitial Aggregates - Experimental Background

- There are three known self-interstitial centres in diamond:
- 1. R2 EPR centre the single self-interstitial (Fig1(a))
- 2. R1 EPR centre the di-self-interstitial (Fig1(b))
- 3. O3 EPR centre the tri-self-interstitial (Fig2(b)) • The 3H optical centre is suspected of being another form of
- the di-interstitial [4, 5]. (Fig1(c)) • The platelets are believed to be large planar aggregates akin
- to Fig 2(c) [4, 6]

# Derivation of $I_1^{\langle 001 \rangle}$ *B*-tensor from Experiment

- Hunt et al reported the populations of different orientations of R2 under stress. [7]
- 0.6 GPa along [100] at 520K leads to a 30% drop in the concentration of R2 parallel to stress.



Fig. 5: Fractional population of x oriented defects at 520K as a function of the magnitude of the x-B-tensor element. for an applied stress of 0.3 and 0.6 GPa along z•  $\Rightarrow B = -24 \text{ eV}$  along the defect axis, 12 eV perpendicular

Summary & Conclusions

• Theory agrees with the measured  $\eta$  (Eq.2) of the A-centre.

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